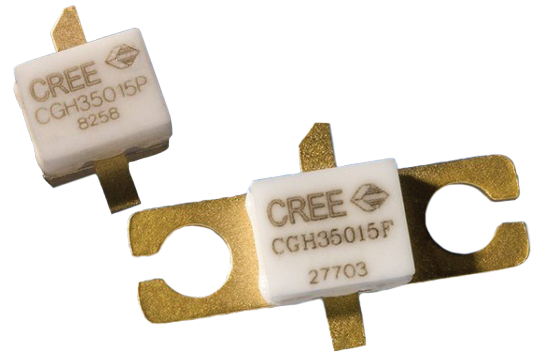


CGH35015

15 W, 3.3-3.9 GHz, 28V, GaN HEMT for WiMAX

Description

Cree's CGH35015 is a gallium nitride (GaN) high electron mobility transistor designed specifically for 802.16-2004 WiMAX Fixed Access applications. GaN HEMTs offer high efficiency, high gain and wide bandwidth capabilities, which makes the CGH35015 ideal for 3.3-3.9 GHz WiMAX and BWA amplifier applications. The transistor is available in both screw-down, flange and solder-down, pill packages.



Package Types: 440166 and 440196
PN's: CGH35015F and CGH35015P

Typical Performance Over 3.3-3.8 GHz ($T_c = 25^\circ\text{C}$) of Demonstration Amplifier

Parameter	3.3 GHz	3.4 GHz	3.5 GHz	3.6 GHz	3.7 GHz	3.8 GHz	Units
Small Signal Gain	13.6	12.8	12.3	12.2	12.3	12.8	dB
EVM at $P_{AVE} = 24\text{ dBm}$	2.71	2.31	2.1	2.12	2.54	3.04	%
EVM at $P_{AVE} = 33\text{ dBm}$	2.63	2.29	1.93	1.70	1.70	2.14	%
Drain Efficiency at $P_{AVE} = 33\text{ dBm}$	24.0	25.5	26.1	25.6	23.8	2.38	%

Note: Measured in the CGH35015F-AMP amplifier circuit, under 802.16 OFDM, 3.5 MHz Channel BW, 1/4 Cyclic Prefix, 64 QAM Modulated Burst, 5 ms Burst, Symbol Length of 59, Coding Type RS-CC, Coding Rate Type 2/3, PAR = 9.8 dB @ 0.01 % Probability on CCDF.

Features

- 3.3 - 3.9 GHz Operation
- 15 W Peak Power Capability
- 12 dB Small Signal Gain
- 2.0 W P_{AVE} at < 2.0% EVM
- 26% Efficiency at 2 W Average Power
- WiMAX Fixed Access 802.16-2004 OFDM
- WiMAX Mobile Access 802.16e OFDMA

 Large Signal Models Available for ADS and MWO

RoHS
COMPLIANT

Absolute Maximum Ratings (not simultaneous) at 25 °C Case Temperature

Parameter	Symbol	Rating	Units	Conditions
Drain-Source Voltage	V_{DS}	120	Volts	25 °C
Gate-to-Source Voltage	V_{GS}	-10, +2	Volts	25 °C
Power Dissipation	P_{DISS}	7	Watts	
Storage Temperature	T_{STG}	-65, +150	°C	
Operating Junction Temperature	T_J	225	°C	
Maximum Forward Gate Current	I_{GMAX}	4.0	mA	25 °C
Maximum Drain Current ¹	I_{DMAX}	1.5	A	25 °C
Soldering Temperature ²	T_S	245	°C	
Screw Torque	τ	40	in-oz	
Thermal Resistance, Junction to Case ³	$R_{\theta JC}$	8.0	°C/W	85 °C
Case Operating Temperature ³	T_C	-40, +150	°C	

Notes:

¹ Current limit for long term, reliable operation

² Refer to the Application Note on soldering at wolfspeed.com/RF/Document-Library

³ Measured for the CGH55015 at $P_{DISS} = 7\text{ W}$

Electrical Characteristics ($T_C = 25\text{ °C}$)

Characteristics	Symbol	Min.	Typ.	Max.	Units	Conditions
DC Characteristics¹						
Gate Threshold Voltage	$V_{GS(th)}$	-3.8	-3.0	-2.3	V_{DC}	$V_{DS} = 10\text{ V}$, $I_D = 3.6\text{ mA}$
Gate Quiescent Voltage	$V_{GS(Q)}$	–	-2.7	–	V_{DC}	$V_{DS} = 28\text{ V}$, $I_D = 60\text{ mA}$
Saturated Drain Current	I_{DS}	2.9	3.5	–	A	$V_{DS} = 6.0\text{ V}$, $V_{GS} = 2.0\text{ V}$
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	84	–	–	V_{DC}	$V_{GS} = -8\text{ V}$, $I_D = 3.6\text{ mA}$
RF Characteristics^{2,3} ($T_C = 25\text{ °C}$, $F_0 = 3.5\text{ GHz}$ unless otherwise noted)						
Small Signal Gain	G_{SS}	10.5	12	–	dB	$V_{DD} = 28\text{ V}$, $I_{DQ} = 100\text{ mA}$
Drain Efficiency ⁴	η	22	26	–	%	$V_{DD} = 28\text{ V}$, $I_{DQ} = 100\text{ mA}$, $P_{AVE} = 2.0\text{ W}$
Back-Off Error Vector Magnitude	EVM_1	–	2.5	–	%	$V_{DD} = 28\text{ V}$, $I_{DQ} = 100\text{ mA}$, $P_{AVE} = 18\text{ dBm}$
Error Vector Magnitude	EVM_2	–	2.5	–	%	$V_{DD} = 28\text{ V}$, $I_{DQ} = 100\text{ mA}$, $P_{AVE} = 2.0\text{ W}$
Output Mismatch Stress	VSWR	–	–	10 : 1	Y	No damage at all phase angles, $V_{DD} = 28\text{ V}$, $I_{DQ} = 100\text{ mA}$, $P_{AVE} = 2.0\text{ W}$
Dynamic Characteristics						
Input Capacitance	C_{GS}	–	4.5	–	pF	$V_{DS} = 28\text{ V}$, $V_{GS} = -8\text{ V}$, $f = 1\text{ MHz}$
Output Capacitance	C_{DS}	–	1.3	–	pF	$V_{DS} = 28\text{ V}$, $V_{GS} = -8\text{ V}$, $f = 1\text{ MHz}$
Feedback Capacitance	C_{GD}	–	0.2	–	pF	$V_{DS} = 28\text{ V}$, $V_{GS} = -8\text{ V}$, $f = 1\text{ MHz}$

Notes:

¹ Measured on wafer prior to packaging

² Measured in the CGH35015F-AMP test fixture

³ Under 802.16 OFDM, 3.5 MHz Channel BW, 1/4 Cyclic Prefix, 64 QAM Modulated Burst, 5 ms Burst, Symbol Length of 59, Coding Type RS-CC, Coding RateType 2/3, PAR = 9.8 dB @ 0.01 % Probability on CCDF

⁴ Drain Efficiency = P_{OUT} / P_{DC}

Typical WiMAX Performance

Figure 1. Small Signal S-Parameters vs Frequency measured in the CGH35015F-AMP
 $V_{DD} = 28\text{ V}$, $I_{DQ} = 100\text{ mA}$

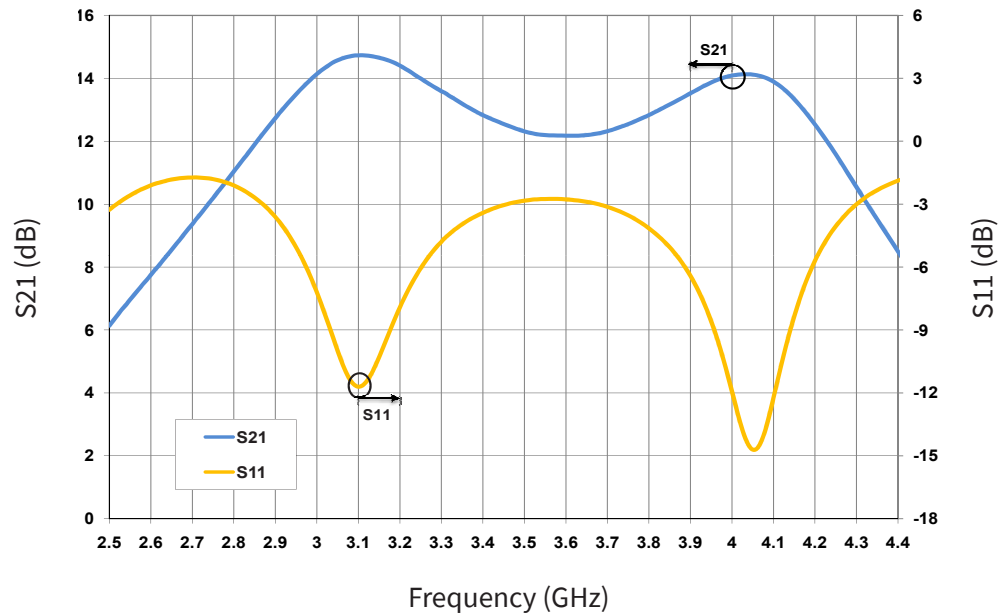
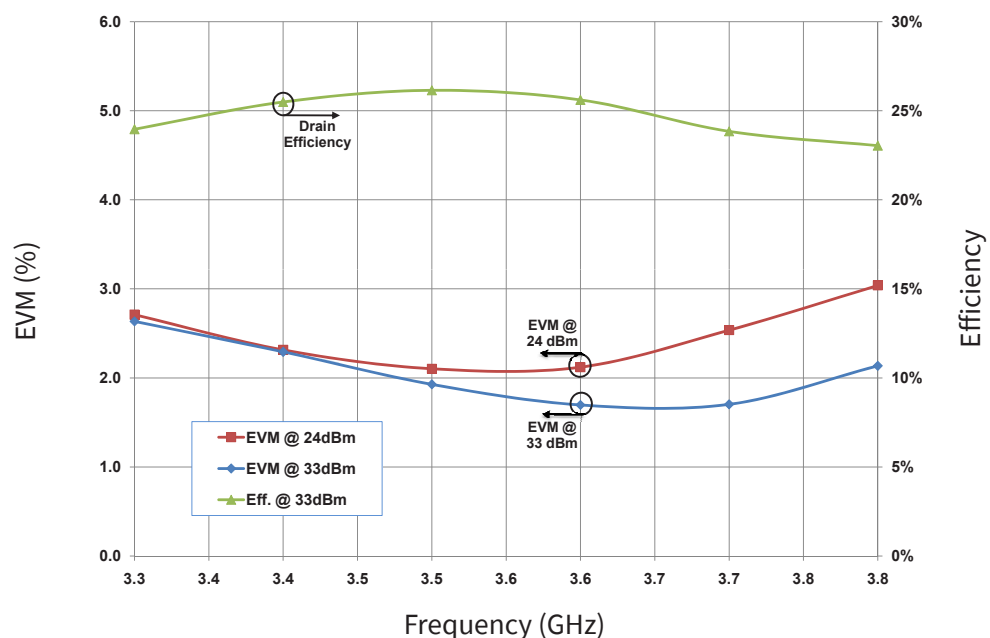


Figure 2. Typical EVM and Efficiency versus Frequency measured in the CGH35015F-AMP
 $V_{DD} = 28\text{ V}$, $I_{DQ} = 100\text{ mA}$, 802.16-2004 OFDM, PAR = 9.8 dB



Note: 802.16 OFDM, 3.5 MHz Channel BW, 1/4 Cyclic Prefix, 64 QAM Modulated Burst, Symbol Length of 59, Coding Type RS-CC, Coding Rate Type 2/3

Typical WiMAX Performance

Figure 3. Drain Efficiency and Gain vs Output Power measured in the CGH35015F-AMP

$V_{DD} = 28\text{ V}$, $I_{DQ} = 100\text{ mA}$, 802.16-2004 OFDM, PAR = 9.8 dB

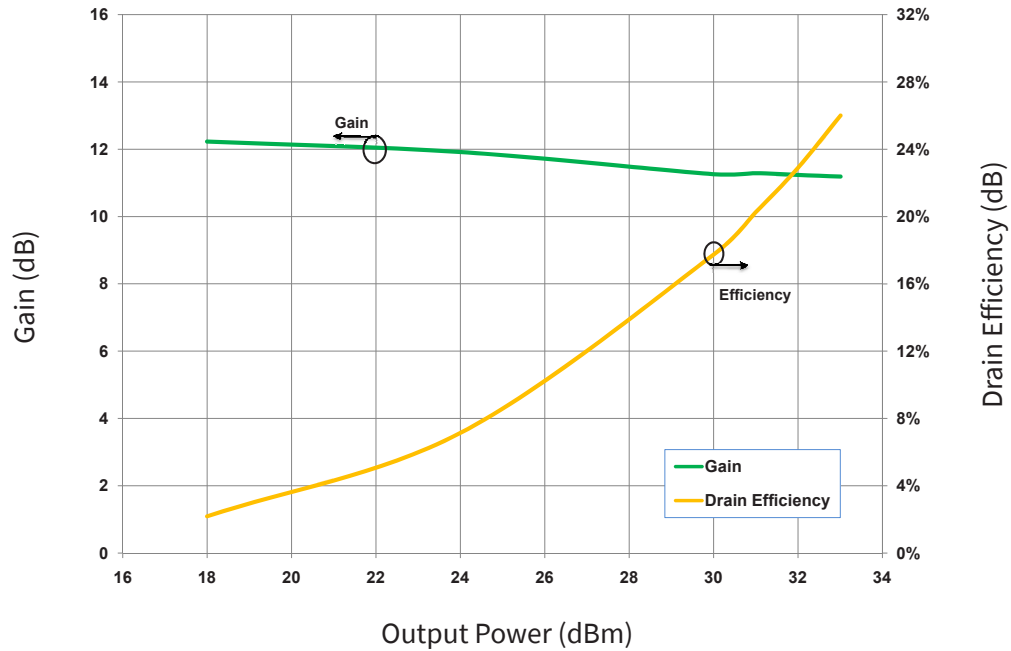
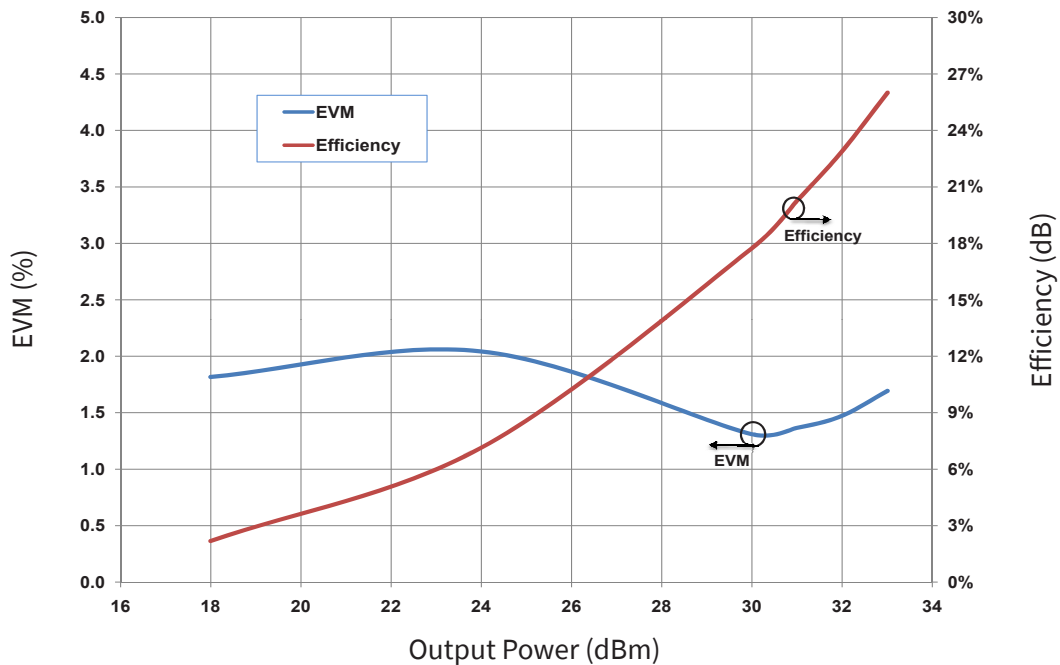


Figure 4. Typical EVM and Efficiency versus Power Output measured in the CGH35015F-AMP

$V_{DD} = 28\text{ V}$, $I_{DQ} = 100\text{ mA}$, 802.16-2004 OFDM, PAR = 9.8 dB

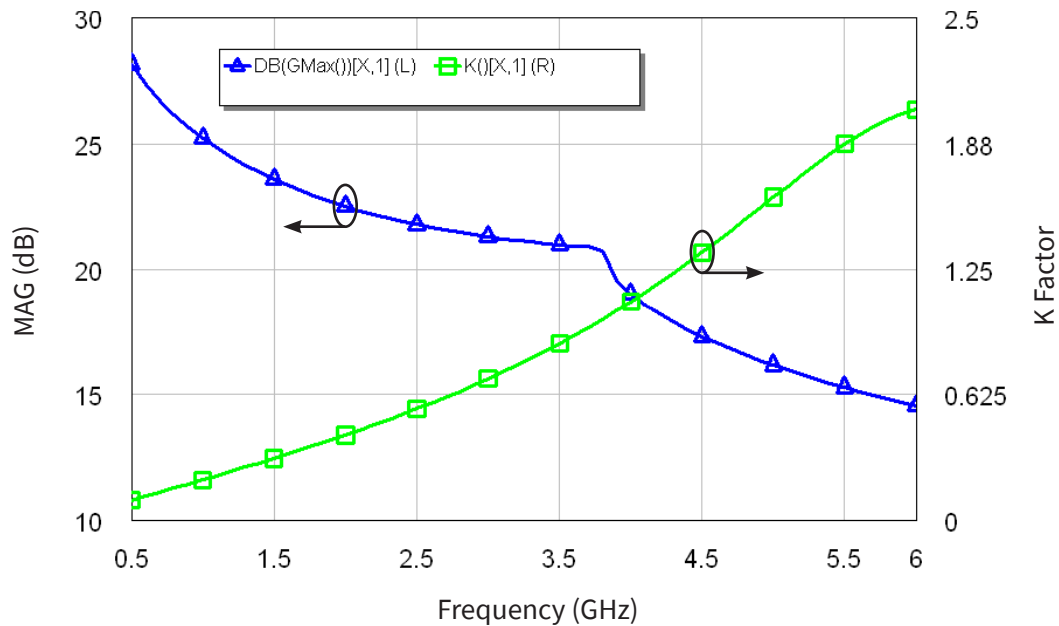


Note: Under 802.16 OFDM, 3.5 MHz Channel BW, 1/4 Cyclic Prefix, 64 QAM Modulated Burst, Symbol Length of 59, Coding Type RS-CC, Coding Rate Type 2/3

Typical Performance

Figure 5. Simulated Maximum Available Gain and K Factor of the CGH35015

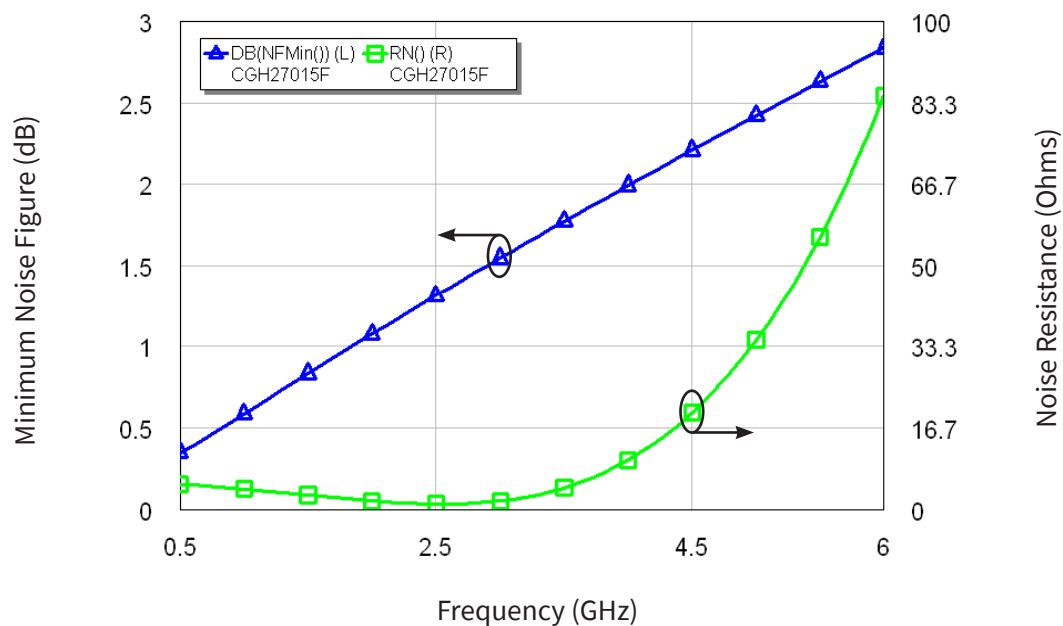
$V_{DD} = 28\text{ V}$, $I_{DQ} = 100\text{ mA}$



Typical Noise Performance

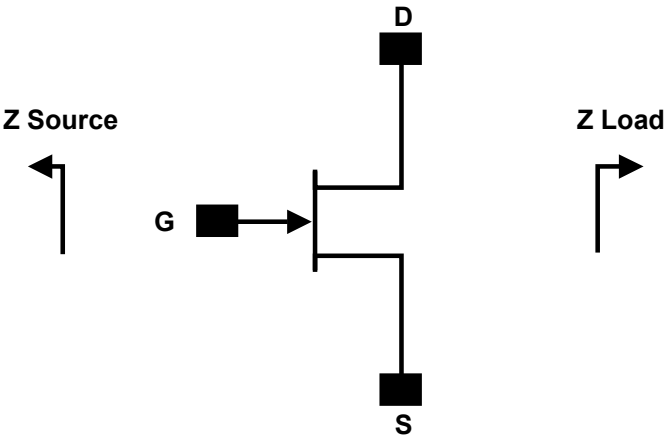
Figure 6. Simulated Minimum Noise Figure and Noise Resistance vs Frequency of the CGH35015

$V_{DD} = 28\text{ V}$, $I_{DQ} = 100\text{ mA}$





Source and Load Impedances



Frequency	Z Source	Z Load
3300	13.0 - j5.6	13.2 - j2.8
3400	17.2 - j6.0	13.2 - j2.8
3500	20.8 - j9.9	13.1 - j2.9
3600	20.1 - j15.8	13.1 - j3.3
3700	15.7 - j19.0	12.3 - j3.8

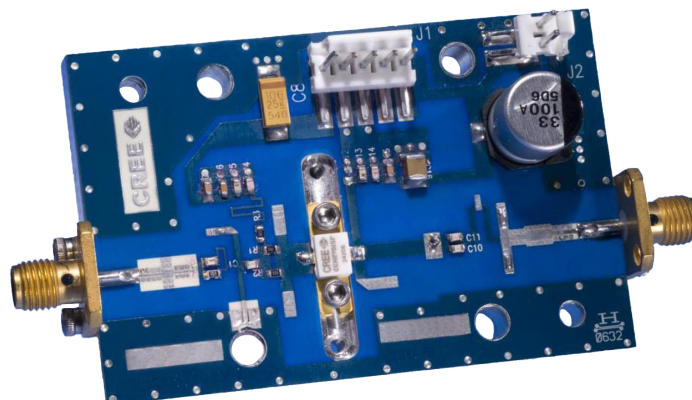
Note 1. $V_{DD} = 28V$, $I_{DQ} = 115\text{ mA}$ in the 440166 package
Note 2. Impedances are extracted from the CGH35015F-AMP demonstration amplifier and are not source and load pull data derived from the transistor

Electrostatic Discharge (ESD) Classifications

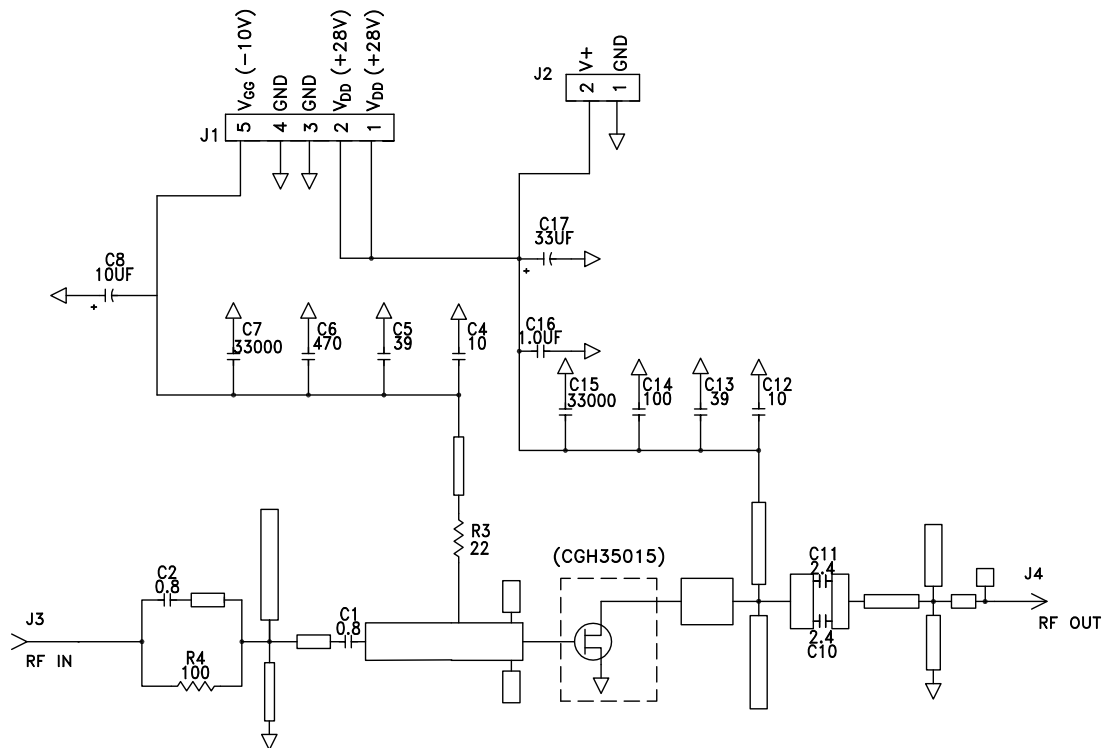
Parameter	Symbol	Class	Test Methodology
Human Body Model	HBM	1A (> 250 V)	JEDEC JESD22 A114-D
Charge Device Model	CDM	II (200 < 500 V)	JEDEC JESD22 C101-C

CGH35015F-AMP Demonstration Amplifier Circuit Bill of Materials

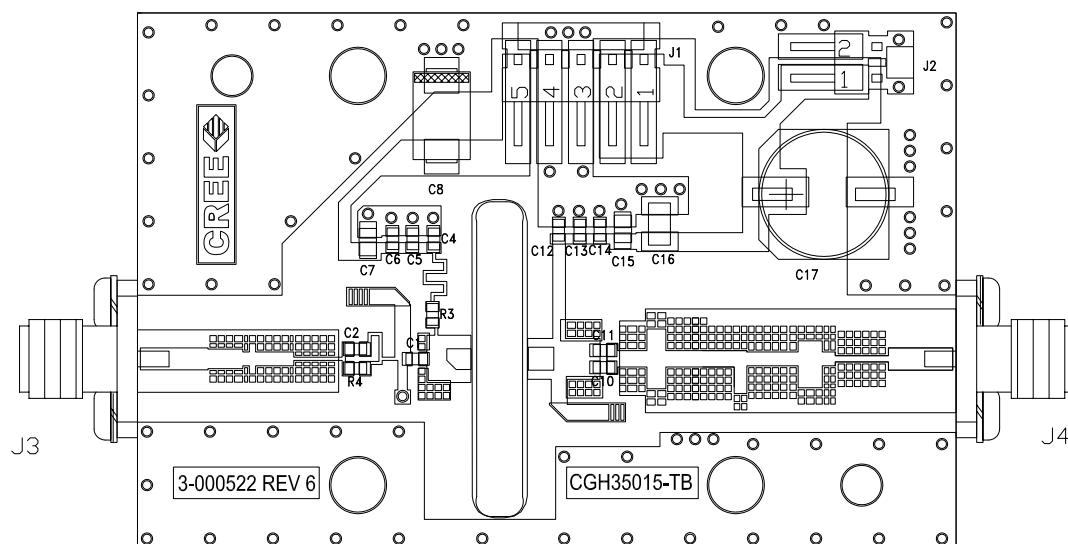
Designator	Description	Qty
C1, C2	CAP, 0.8pF, +/-0.1 pF, 0603, ATC 600S	2
C10, C11	CAP, 2.4pF, +/-0.1pF, 0603, ATC 600S	2
C4, C12	CAP, 10.0pF, +/-5%, 0603, ATC 600S	1
C5, C13	CAP, 39 PF±5%, 0603, ATC 600S	2
C14	CAP, 100 PF±5%, 0603, ATC 600S	1
C6	CAP, 470 PF ±10%, 100 V, 0603	1
C7, C15	CAP, 33000PF, 100V, 0805, X7R	2
C8	CAP, 10UF, 16V, SMT, TANTALUM (240096)	1
C16	CAP, 1.0UF ±10%, 100V, 1210, X7R	1
C17	CAP, 33UF, 100V, ELECT, FK, SMD	1
R3	RES, 1/16W, 0603, 22 Ohms ≤5%	1
R4	RES, 1/16W, 0603, 100 Ohms ≤5%	1
J1	5-PIN, MOLEX, MALE, CONNECTOR	1
J2	2-PIN, MOLEX, MALE, CONNECTOR	1
J3, J4	SMA, FEMALE, CONNECTOR	2
-	PCB, RO4350B, Er = 3.48, h = 20 mil	1
-	CGH35015F or CGH35015P	1

CGH35015F-AMP Demonstration Amplifier Circuit

CGH35015-AMP Demonstration Amplifier Circuit Schematic



CGH35015-AMP Demonstration Amplifier Circuit Outline



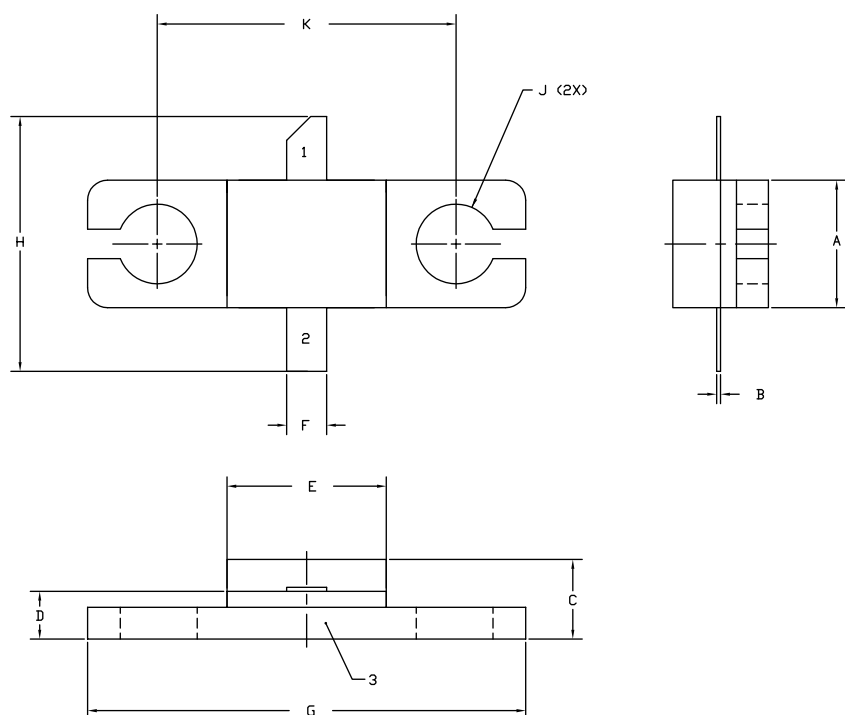


Typical Package S-Parameters for CGH35015
 (Small Signal, $V_{DS} = 28\text{ V}$, $I_{DQ} = 100\text{ mA}$, angle in degrees)

Frequency	Mag S11	Ang S11	Mag S21	Ang S21	Mag S12	Ang S12	Mag S22	Ang S22
500 MHz	0.909	-124.41	17.41	107.81	0.026	21.06	0.335	-93.73
600 MHz	0.902	-134.04	15.04	101.48	0.027	15.39	0.322	-101.61
700 MHz	0.898	-141.62	13.18	96.16	0.028	10.74	0.315	-107.78
800 MHz	0.894	-147.78	11.71	91.54	0.028	6.79	0.312	-112.73
900 MHz	0.892	-152.91	10.51	87.43	0.028	3.35	0.312	-116.77
1.0 GHz	0.890	-157.30	9.53	83.68	0.028	0.28	0.314	-120.15
1.1 GHz	0.889	-161.12	8.71	80.20	0.028	-2.51	0.318	-123.04
1.2 GHz	0.889	-164.51	8.01	76.95	0.028	-5.07	0.322	-125.57
1.3 GHz	0.888	-167.56	7.41	73.86	0.028	-7.45	0.328	-127.82
1.4 GHz	0.888	-170.34	6.89	70.91	0.028	-9.69	0.335	-129.87
1.5 GHz	0.888	-172.91	6.44	68.07	0.028	-11.81	0.342	-131.77
1.6 GHz	0.888	-175.30	6.04	65.32	0.028	-13.82	0.349	-133.56
1.7 GHz	0.888	-177.55	5.69	62.65	0.027	-15.74	0.357	-135.25
1.8 GHz	0.888	-179.68	5.37	60.05	0.027	-17.58	0.364	-136.89
1.9 GHz	0.888	178.29	5.09	57.50	0.027	-19.34	0.373	-138.48
2.0 GHz	0.888	176.34	4.83	55.01	0.027	-21.04	0.381	-140.03
2.1 GHz	0.889	174.45	4.60	52.56	0.026	-22.69	0.389	-141.55
2.2 GHz	0.889	172.63	4.39	50.14	0.026	-24.27	0.397	-143.06
2.3 GHz	0.889	170.84	4.20	47.76	0.026	-25.80	0.405	-144.56
2.4 GHz	0.889	169.10	4.02	45.41	0.025	-27.28	0.413	-146.04
2.5 GHz	0.890	167.39	3.86	43.09	0.025	-28.70	0.421	-147.52
2.6 GHz	0.890	165.71	3.71	40.79	0.025	-30.08	0.429	-149.00
2.7 GHz	0.891	164.04	3.57	38.51	0.024	-31.41	0.437	-150.48
2.8 GHz	0.891	162.39	3.44	36.26	0.024	-32.69	0.445	-151.95
2.9 GHz	0.891	160.76	3.32	34.01	0.024	-33.92	0.452	-153.43
3.0 GHz	0.892	159.13	3.21	31.79	0.023	-35.10	0.459	-154.92
3.2 GHz	0.892	155.89	3.00	27.38	0.023	-37.31	0.473	-157.90
3.4 GHz	0.893	152.65	2.83	23.00	0.022	-39.32	0.486	-160.90
3.6 GHz	0.893	149.39	2.67	18.66	0.021	-41.09	0.499	-163.93
3.8 GHz	0.894	146.09	2.54	14.34	0.020	-42.63	0.510	-166.99
4.0 GHz	0.894	142.74	2.41	10.02	0.020	-43.90	0.521	-170.10
4.2 GHz	0.895	139.33	2.31	5.70	0.019	-44.88	0.530	-173.24
4.4 GHz	0.895	135.84	2.21	1.37	0.018	-45.53	0.539	-176.45
4.6 GHz	0.895	132.26	2.12	-2.98	0.018	-45.84	0.547	-179.71
4.8 GHz	0.895	128.59	2.04	-7.36	0.017	-45.78	0.554	176.97
5.0 GHz	0.895	124.80	1.97	-11.79	0.016	-45.32	0.561	173.56
5.2 GHz	0.895	120.90	1.91	-16.27	0.016	-44.47	0.566	170.07
5.4 GHz	0.895	116.87	1.85	-20.81	0.016	-43.25	0.571	166.48
5.6 GHz	0.895	112.70	1.80	-25.41	0.015	-41.72	0.575	162.78
5.8 GHz	0.895	108.38	1.75	-30.10	0.015	-39.97	0.579	158.96
6.0 GHz	0.895	103.92	1.70	-34.88	0.016	-38.13	0.581	155.00

To download the s-parameters in s2p format, go to the [CGH35015](#) Product page and click on the documentation tab.

Product Dimensions CGH35015F (Package Type — 440166)



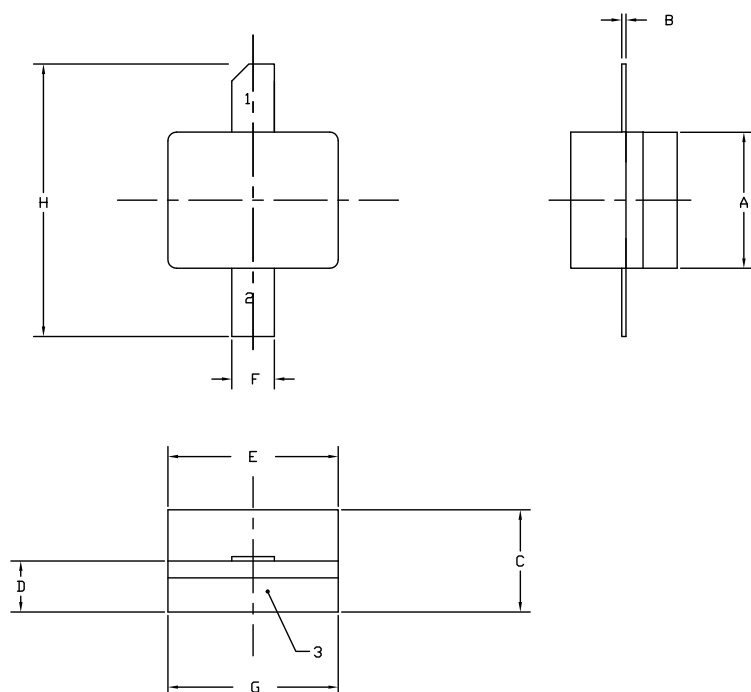
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. ADHESIVE FROM LID MAY EXTEND A MAXIMUM OF 0.020" BEYOND EDGE OF LID.
4. LID MAY BE MISALIGNED TO THE BODY OF THE PACKAGE BY A MAXIMUM OF 0.008" IN ANY DIRECTION.
5. ALL PLATED SURFACES ARE NI/AU

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.155	0.165	3.94	4.19
B	0.004	0.006	0.10	0.15
C	0.115	0.135	2.92	3.43
D	0.057	0.067	1.45	1.70
E	0.195	0.205	4.95	5.21
F	0.045	0.055	1.14	1.40
G	0.545	0.555	13.84	14.09
H	0.280	0.360	7.11	9.14
J	Ø .100		2.54	
K	0.375		9.53	

- PIN 1. GATE
PIN 2. DRAIN
PIN 3. SOURCE

Product Dimensions CGH35015P (Package Type — 440196)



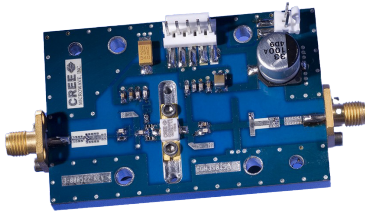
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5. ALL PLATED SURFACES ARE NI/AU

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.155	0.165	3.94	4.19
B	0.003	0.006	0.10	0.15
C	0.115	0.135	2.92	3.17
D	0.057	0.067	1.45	1.70
E	0.195	0.205	4.95	5.21
F	0.045	0.055	1.14	1.40
G	0.195	0.205	4.95	5.21
H	0.280	0.360	7.11	9.14

- PIN 1. GATE
PIN 2. DRAIN
PIN 3. SOURCE

Product Ordering Information

Order Number	Description	Unit of Measure	Image
CGH35015F	GaN HEMT	Each	
CGH35015P	GaN HEMT	Each	
CGH35015-AMP	Test board with GaN HEMT installed	Each	

For more information, please contact:

4600 Silicon Drive
Durham, North Carolina, USA 27703
www.wolfspeed.com/RF

Sales Contact
RFSales@cree.com

Notes

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Specifications are subject to change without notice. “Typical” parameters are the average values expected by Cree in large quantities and are provided for information purposes only. Cree products are not warranted or authorized for use as critical components in medical, life-saving, or life-sustaining applications, or other applications where a failure would reasonably be expected to cause severe personal injury or death. No responsibility is assumed by Cree for any infringement of patents or other rights of third parties which may result from use of the information contained herein. No license is granted by implication or otherwise under any patent or patent rights of Cree.

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